

# SEMIPONT<sup>TM</sup> 5

### **Bridge Rectifier**

#### **SKDT 145**

**Target Data** 

#### **Features**

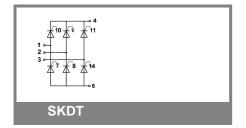
- Compact design
- · Two screws mounting
- Heat transfer and isolation through direct copper board (low R<sub>th</sub>)
- Low resistance in steady-state and high reliability
- · High surge currents
- Glass passivated thyristor chips
- Up to 1600 V reverse voltage
- UL -recognized, file no. E 63 532

#### **Typical Applications**

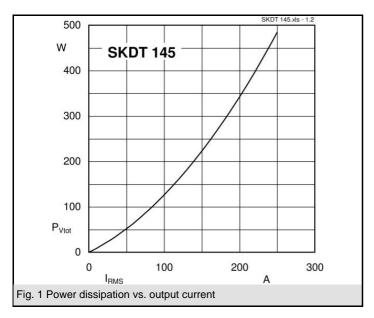
- DC and AC drives
- Controlled field rectifier for DC motors
- Controlled battery charger

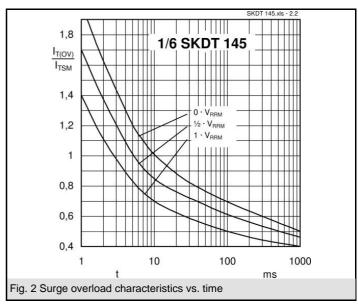
V <sub>RSM</sub>	V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>D</sub> = 140 A (full conduction)
1300	1200	(T <sub>s</sub> = 80 °C) SKDT 145/12
1700	1600	SKDT 145/16

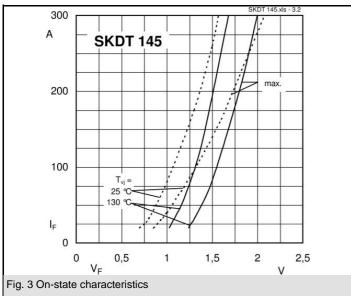
Symbol	Conditions	Values	Units
I <sub>D</sub>	T <sub>s</sub> = 80 °C	140	Α
I <sub>TSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	1350	Α
TOW	T <sub>vi</sub> = 125 °C; 10 ms	1250	Α
i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	9000	A²s
	T <sub>vj</sub> = 125 °C; 8,3 10 ms	7800	A²s
V <sub>T</sub>	T <sub>vj</sub> = 25 °C; I <sub>T</sub> = 150A	max. 1,6	V
$V_{T(TO)}$	$T_{vj} = 125 ^{\circ}\text{C};$	max. 0,9	V
$r_T$	T <sub>vj</sub> = 125 °C	max. 5	mΩ
$I_{DD}; I_{RD}$	$T_{vj}$ = 125 °C; $V_{DD}$ = $V_{DRM}$ ; $V_{RD}$ = $V_{RRM}$	max. 20	mA
t <sub>gd</sub>	$T_{vj} = {^{\circ}C}; I_G = A; di_G/dt = A/\mu s$		μs
$t_{gr}$	$V_D = \cdot V_{DRM}$		μs
(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 500	V/µs
(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C; f = 5060 Hz	max. 50	A/µs
$t_q$	$T_{vj} = 125 ^{\circ}\text{C}; \text{ typ.}$	150	μs
I <sub>H</sub>	$T_{vj}$ = 25 °C; typ. / max.	- / 250	mA
IL	$T_{vj}$ = 25 °C; $R_G$ = 33 $\Omega$	- / 600	mA
V <sub>GT</sub>	T <sub>vj</sub> = 25 °C; d.c.	min. 3	V
$I_{GT}$	$T_{vj} = 25  ^{\circ}\text{C}; \text{d.c.}$	min. 150	mA
$V_{GD}$	$T_{vj} = 125 ^{\circ}\text{C}; \text{d.c.}$	max. 0,25	V
$I_{GD}$	T <sub>vj</sub> = 125 °C; d.c.	max. 6	mA
			K/W
			K/W
$R_{th(j-s)}$	per thyristor	0,6	K/W
T <sub>vi</sub>		- 40 <b>+</b> 125	°C
T <sub>stg</sub>		- 40 <b>+</b> 125	°C
T <sub>solder</sub>	terminals	260	°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 ( 3000 )	V
M <sub>s</sub>	to heatsink	2,5	Nm
$M_t$			Nm
m	approx.	75	g
Case		G 58	

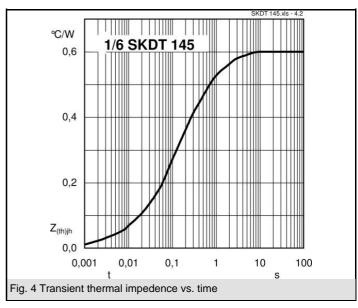


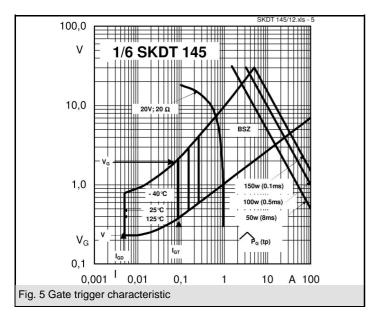
## **SKDT** 145



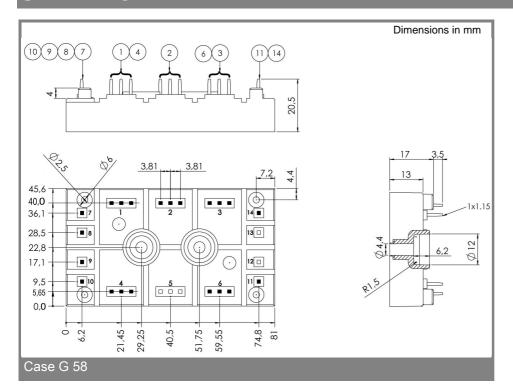


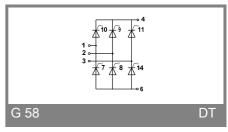






### **SKDT 145**





This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.